



DMN3009SFG

Product Summary

BV _{DSS}	Rds(on) Max	I⊳ Max Tc = +25°C	
	5.5mΩ @ V _{GS} = 10V	45A	
30V	9mΩ @ V _{GS} = 4.5V	30A	

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Power Management Functions
- DC-DC Converters
- Battery

30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
- https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate
 Datasheet (DMN3009SFGQ)

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)

PowerDI3333-8



Ordering Information (Note 4)

	Part Number	Case	Packaging
	DMN3009SFG-7	PowerDI3333-8	2,000/Tape & Reel
DMN3009SFG-13 PowerDI3333-8 3,000/Tape & Reel			

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



N09= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	30	V	
Gate-Source Voltage	Vgss	±20	V	
	T _A = +25°C		16	А
	$T_A = +70^{\circ}C$	I _D	13	
Continuous Drain Current, V _{GS} = 10V (Note 6)	Tc = +25°C		45	А
	Tc = +70°C	ID	35	
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	Ідм	80	А	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	20	А	
Avalanche Current, L = 0.1mH	las	33	А	
Avalanche Energy, L = 0.1mH	Eas	55	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit		
Total Dower Dissinction (Note 5)	T _A = +25°C	D-	0.9	W	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.6		
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	137	°C/W		
Total Dower Dissinction (Nate C)	T _A = +25°C	Po	2.1	W	
Total Power Dissipation (Note 6)	T _A = +70°C	гD	1.4	vv	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	59	°C/W	
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	7.8	°C/W		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

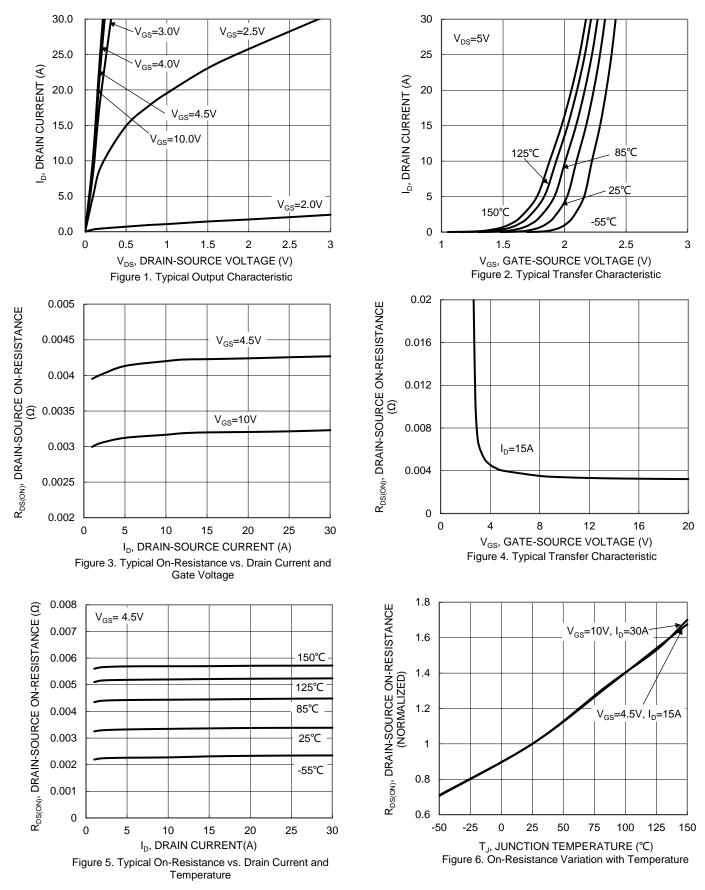
Characteristic	Symbol	Min	Turn	Мах	Unit	Test Condition	
	Symbol	IVIIII	Тур	Widx	Unit	Test condition	
OFF CHARACTERISTICS (Note 6)			1				
Drain-Source Breakdown Voltage	BVDSS	30	—	—	V	Vgs = 0V, ID = 250µA	
Zero Gate Voltage Drain Current	IDSS	—	—	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	VGS(TH)	1	—	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Descent	_	3.4	5.5	mΩ	Vgs = 10V, ID = 20A	
	Rds(on)		4.4	9	11152	V _{GS} = 4.5V, I _D = 16A	
Diode Forward Voltage	V _{SD}		0.7	1	V	$V_{GS} = 0V, I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	2,000		pF		
Output Capacitance	Coss	_	315		pF	− V _{DS} = 15V, V _{GS} = 0V, − f = 1MHz	
Reverse Transfer Capacitance	Crss	_	248		pF		
Gate Resistance	Rg	_	2.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	20	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg		42	_	nC		
Gate-Source Charge	Q _{gs}	_	4.7	_	nC	VDS = 15V, ID = 15A	
Gate-Drain Charge	Q _{gd}	_	7.4	_	nC		
Turn-On Delay Time	t _{D(ON)}	—	3.9	_	ns		
Turn-On Rise Time	tR	_	4.1	_	ns	V _{DD} = 15V, V _{GS} = 10V,	
Turn-Off Delay Time	tD(OFF)	_	31		ns	R _G = 3.3Ω, I _D = 15A	
Turn-Off Fall Time	tF	_	14.6		ns	7	
Reverse Recovery Time	t _{RR}		15		ns		
Reverse Recovery Charge	Qrr		6	_	nC	I _F = 15A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect. Notes:

DMN3009SFG Document number: DS36747 Rev. 7 - 2

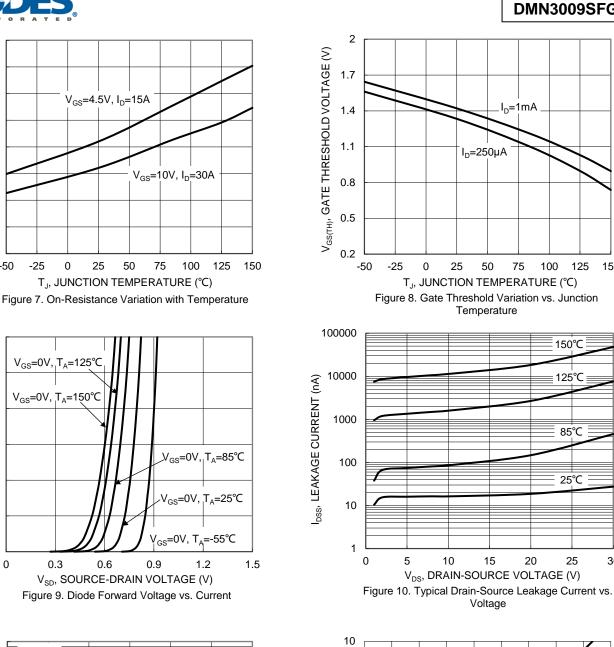


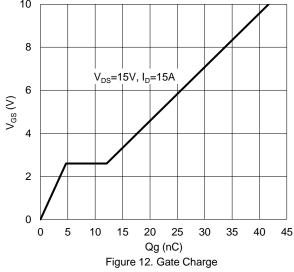
DMN3009SFG



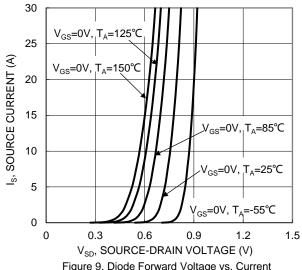
DMN3009SFG Document number: DS36747 Rev. 7 - 2







0.008 R_{DS(ON)}, DRAIN-SOURCE ON-RESISTANCE 0.007 0.006 0.005 g 0.004 0.003 0.002 0.001 0 -50 -25 T_., JUNCTION TEMPERATURE (°C)



10000 f=1MHz C_T, JUNCTION CAPACITANCE (pF) $\mathbf{C}_{\mathrm{iss}}$ 1000 C_{oss} $\mathbf{C}_{\mathrm{rss}}$ 100 0 10 20 5 15 25 30 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 11. Typical Junction Capacitance

DMN3009SFG

I_D=1mA

75

100

125

150[°]C

125°C

85°℃

25℃

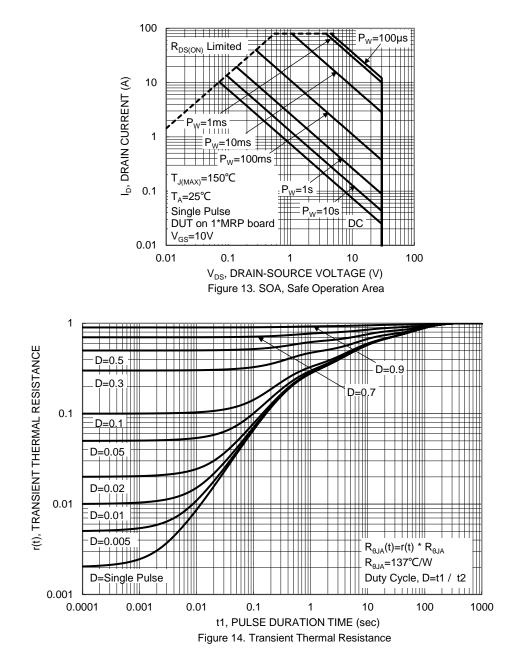
25

30

20

150

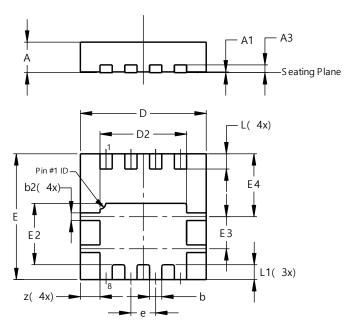






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

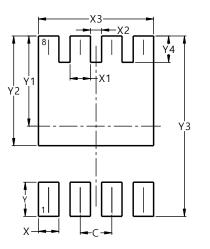


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	-	-	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
z	_	_	0.515		
All I	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540

PowerDI3333-8



IMPORTANT NOTICE

1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

5 products provided to Diodes' Standard Terms and Conditions of Sale Diodes are subject (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com